



HIGH-VOLTAGE, HIGH-SENSITIVITY AUTOMOTIVE HALL EFFECT LATCH

Description

The AH3762Q is an AEC-Q100 qualified high-voltage, high-sensitivity Hall-Effect latch IC designed for brushless DC-motor commutation speed measurement, angular or linear encoders and position sensors in automotive applications. To support a wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3762Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

The single, open-drain output can be switched on with South pole of sufficient strength and switched off with North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (Bop) the output is switched on (pulled low). The output is held latched until magnetic flux density reverses and becomes lower than the release point (Brp).

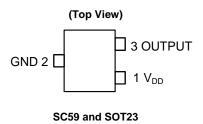
The magnetic operating and release polarity is opposite for SOT23 and SC59 packages. SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) packages will require south pole to the part marking side to operate while SC59 will require south pole to the non part-marking side.

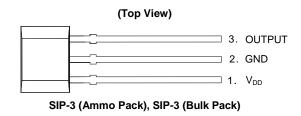
Features

- Bipolar Latch Operation (South Pole: On, North Pole: Off)
- High Sensitivity: Bop and Brp of +25G and -25G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- · Chopper Stabilized Design Provides
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Good RF Noise Immunity
- · Reverse Blocking Diode
- · Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM > 8kV, CDM > 2kV
- AEC-Q100 Grade 0 Qualified
- Industry Standard SC59, SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green Device (Note 3)
- The AH3762Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Pin Assignments





Applications

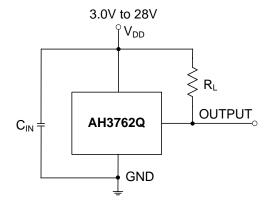
- · Brushless DC-Motor Commutation
- Revolution Per Minute (RPM) Measurement
- Angular and Linear Encoder and Position Sensing and Indexing
- Flow Meters
- Contactless Commutation, Speed Measurement and Angular Position Sensing/Indexing in Automotive Applications

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit (Note 4)



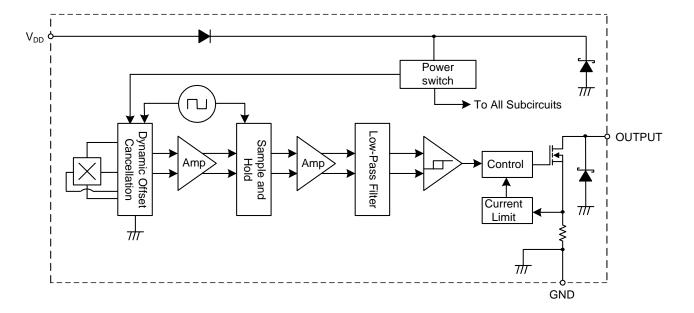
Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF to 100nF. R_L is the pull-up resistor.

Pin Descriptions

Package: SC59, SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	V_{DD}	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

Functional Block Diagram





Absolute Maximum Ratings (Notes 5 and 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit
VDD	Supply Voltage (Note 6)		32	V
Vddr	Reverse Supply Voltage (Note 6)		-32	V
Vout_max	Output Off Voltage (Note 6)	32	V	
lout	Continuous Output Current	60	mA	
I _{OUT_R}	Reverse Output Current	-50	mA	
В	Magnetic Flux Density	Unlimited		
PD	Package Power Dissipation	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	550	mW
		SC59 and SOT23	230	
Ts	Storage Temperature Range		-65 to +165	°C
TJ	Maximum Junction Temperature		+150	°C
ESD HBM	Electros Static Discharge Withstand – Human Body Model (H	HBM)	8	kV
ESD MM	Electros Static Discharge Withstand - Machine Model (MM)		800	V
ESD CDM	Electros Static Discharge Withstand - Charged Device Mode	I (CDM)	2	kV

Notes:

Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V _{DD}	Supply Voltage	Operating	3.0 to 28	V
T _A	Operating Temperature Range	Operating	-40 to +150	°C

Electrical Characteristics (Notes 7 and 8) (@T_A = -40°C to +150°C, V_{DD} = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Vout_on	Output ON Voltage	IOUT = 20mA, B > Bop	_	0.2	0.4	V
ILKG	Output Leakage Current (When Output is Off)	Vout = 28V, B < Brp, Output Off	_	<0.1	10	μΑ
IDD	Supply Current	Output Open, T _A = +25°C	_	3	3.5	mA
		Output Open, T _A = -40 to +150°C	_	—	4	mA
		$V_{DD} = -18V, T_A = +25^{\circ}C$	_	0.6	_	μΑ
IDD R	Reverse Supply Current	$V_{DD} = -18V$, $T_A = -40$ to $+150$ °C	_	0.6	1,500	μΑ
IDD_K	Reverse Supply Current	$V_{DD} = -28V, T_A = +25^{\circ}C$	_	1.6	_	μΑ
		$V_{DD} = -28V$, $T_A = -40$ to $+150$ °C	_	1.6	2,500	μΑ
tp_on	Device Power-On Time (Start-Up Time)	V _{DD} >= 3V, B > Bop (Note 8)	_	10	_	μs
f _c	Chopping Frequency	$V_{DD} >= 3V$	_	800	_	kHz
t _d	Response Time Delay (Time from Magnetic Threshold Reached to the Start of the Output Rise or Fall)	(Note 9)	_	3.75	_	μs
t _r	Output Rising Time (External Pull-Up Resistor R∟and Load Capacitance Dependent)	$R_L = 1k\Omega$, $C_L = 20pF$	_	0.2	1	μs
t _f	Output Falling Time (Internal Switch Resistance and load capacitance dependent)	$R_L = 1k\Omega$, $C_L = 20pF$	_	0.1	1	μs
locL	Output Current Limit	B > Bop (Note 10)	30	_	55	mA
Vz	Zener Clamp Voltage	$I_{DD} = 5mA$	28	_	_	V

Notes:

^{5.} Stresses greater than the 'Absolute Maximum Ratings' specified above can cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability can be affected by exposure to absolute maximum rating conditions for extended periods of time.

^{6.} The absolute maximum V_{DD} of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

^{7.} When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

^{8.} Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range are not tested in production but guaranteed by design, process control and characterization.

^{9.} Guaranteed by design, process control and characterization. Not tested in production.

^{10.} The device will limit the output current I_{OUT} to current limit of I_{OCL} .

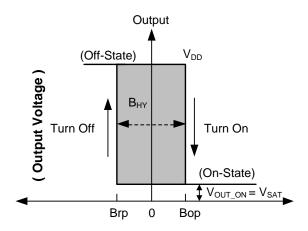


Magnetic Characteristics (Notes 11 and 12) (T_A = -40°C to +150°C, V_{DD} = 3.0V to 28V, unless otherwise specified.)

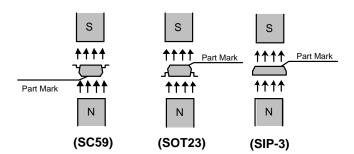
				(1mT=10 G	auss)
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Bop (South pole to part marking side for SOT23 and SIP-3 (Ammo Pack), SIP-3		V _{DD} = 12V, T _A = +25°C	_	25	_	
(Bulk Pack) packages; South pole to the non-part marking side for SC59 package. See diagram below)	Operation Point	T _A = -40°C to +150°C	10	25	40	
Brp (North pole to part marking side for		V _{DD} = 12V, T _A = +25°C	_	-25	_	Gauss
SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) packages; North pole to the non-part marking side for SC59 package. See diagram below)	Release Point	T _A = -40°C to +150°C	-40	-25	-10	Gauss
B _{HY} (Bopx - Brpx)	Hysteresis (Note 13)	V _{DD} = 12V, T _A = +25°C	_	50	_	
	Trysteresis (Note 15)	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	20	50	80	

Notes:

- 11. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.
- 12. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.



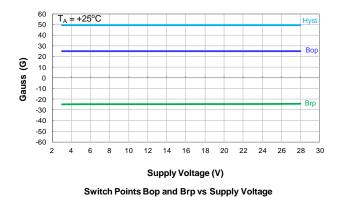
(Magnetic Flux Density B)

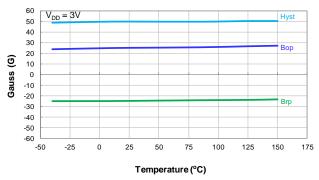




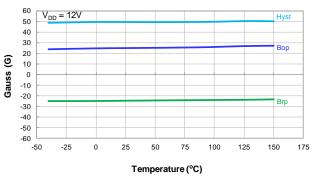
Typical Operating Characteristics

Output Switch Operate and Release Points (Magnetic Thresholds) – Bop and Brp

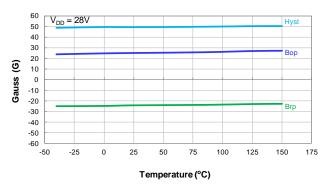




Switch Points Bop and Brp vs Temperature

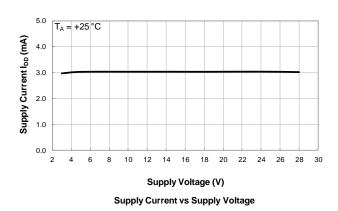


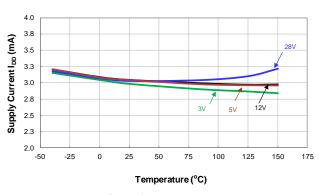
Switch Points Bop and Brp vs Temperature



Switch Points Bop and Brp vs Temperature

Supply Current



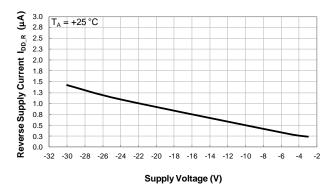


Supply Current vs Temperature

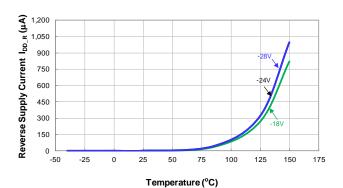


Typical Operating Characteristics (continued)

Reverse Supply Current

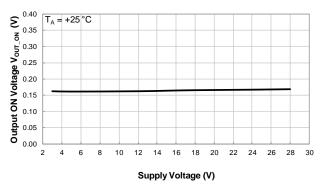


Reverse Supply Current vs Supply Voltage

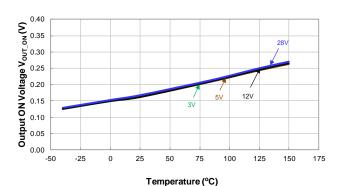


Reverse Supply Current vs Temperature

Output Switch On Voltage

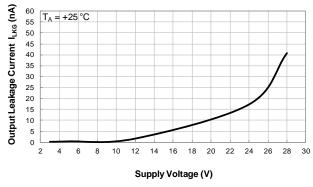


Output ON Voltage vs Supply Voltage

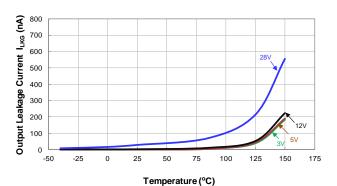


Output ON Voltage vs Temperature

Output Switch Leakage Current



Output Leakage Current vs Supply Voltage

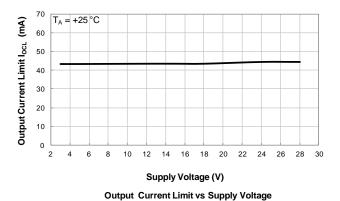


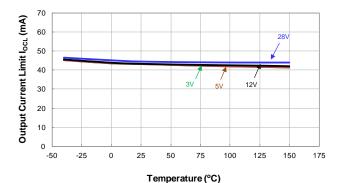
Output Leakage Current vs Temperature



Typical Operating Characteristics (continued)

Output Current Limit





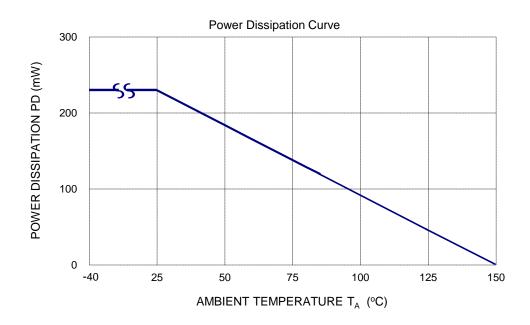
Output Current Limit vs Temperature



Thermal Performance Characteristics

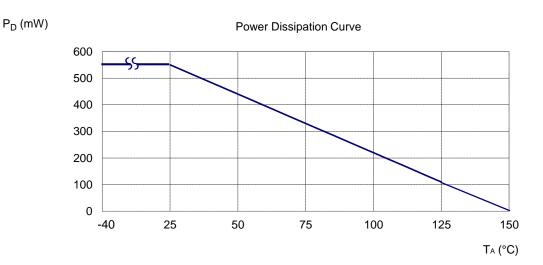
(1) Package Type: SC59 and SOT23

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



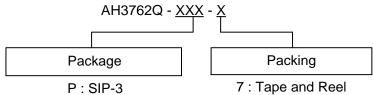
(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





Ordering Information



SA: SOT23 W: SC59

A: Ammo Box (Note 14) B: Bulk (Note 15)

				Вι	ılk	7" Tape	and Reel	Ammo	Вох
Part Number	Status	Package Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix
AH3762Q-P-A	Active	Р	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	NA	NA	NA	NA	4,000/Box	-A
AH3762Q-P-B	Active	Р	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	1,000	-B	NA	NA	NA	NA
AH3762Q-SA-7	NRND (Note 16)	SA	SOT23	NA	NA	3,000/Tape & Reel	-7	NA	NA
AH3762Q-W-7	NRND (Note 16)	W	SC59	NA	NA	3,000/Tape & Reel	-7	NA	NA

Notes:

- 14. Ammo Box is for SIP-3 Spread Lead.
- 15. Bulk is for SIP-3 Straight Lead.
- 16. NRND = Not Recommended for New Design.

Marking Information

(1) Package Type: SC59 and SOT23



XX Y W X

XX: Identification Code

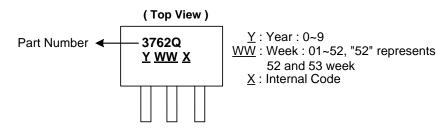
Y: Year 0 to 9

W: Week: A to Z: 1 to 26 week; a to z: 27 to 52 week; z represents 52 and 53 week

X: Internal Code

Part Number	Package	Identification Code
AH3762Q	SC59	YK
AH3762Q	SOT23	WK

(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)



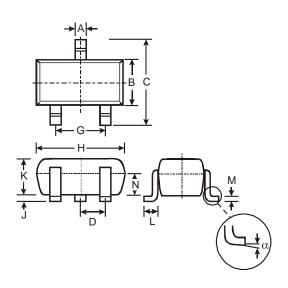
Part Number	Package	Identification Code
AH3762Q	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	3762Q



Package Outline Dimensions (All dimensions in mm.)

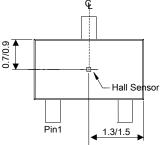
Please see http://www.diodes.com/package-outlines.html for the latest version.

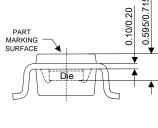
(1) Package Type: SC59



	SC	59			
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
С	2.70	3.00	2.80		
D	-	-	0.95		
G	-	-	1.90		
Н	2.90	3.10	3.00		
J	0.013	0.10	0.05		
K	1.00	1.30	1.10		
L	0.35	0.55	0.40		
М	0.10	0.20	0.15		
N	0.70	0.80	0.75		
α	0°	8°	-		
All	Dimens	ions in	mm		







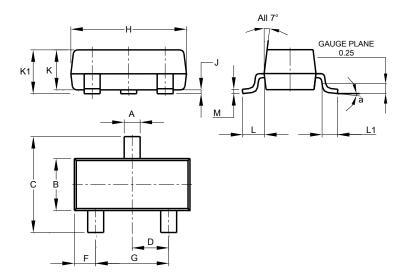
Sensor Location



Package Outline Dimensions (continued) (All dimensions in mm.)

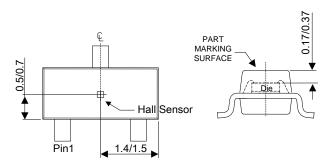
Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: SOT23



	so	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а	0°	8°	
All	Dimens	ions in	mm

Min/Max



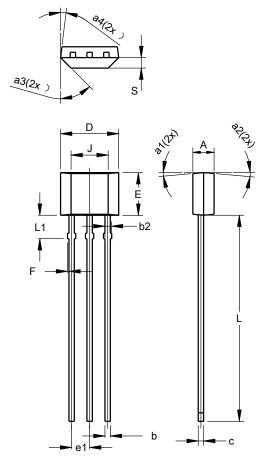
Sensor Location



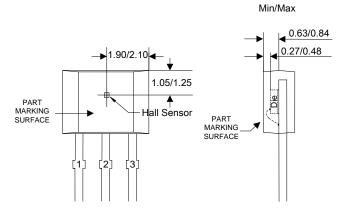
Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type: SIP-3 (Bulk Pack)



SIP-3 (Bulk Pack)				
Dim	Min	Max	Тур	
Α	1.40	1.60	1.50	
b	0.33	0.43	0.38	
b2	0.40	0.508	0.46	
С	0.35	0.41	0.38	
D	3.90	4.30	4.10	
E	2.80	3.20	3.00	
e1	1.24	1.30	1.27	
F	0.00	0.20	_	
J	2.62 REF			
L	14.00	15.00	14.50	
L1	1.55	1.75	1.65	
S	0.63	0.84	0.74	
a1	_	_	5°	
a2	_	_	5°	
а3	_	_	45°	
a4	_	_	3°	
All Dimensions in mm				



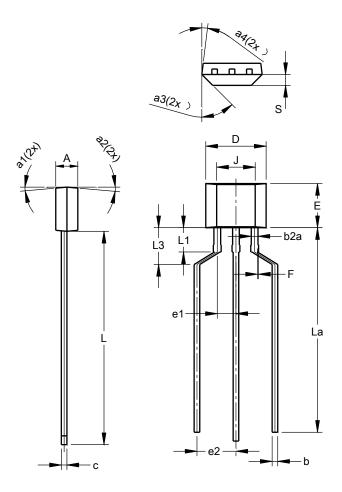
Sensor Location



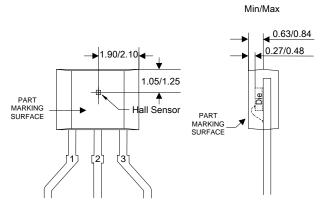
Package Outline Dimensions (continued) (All dimensions in mm.)

 $\label{please} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

(4) Package Type: SIP-3 (Ammo Pack)



SIP-3					
(Ammo Pack)					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
b	0.33	0.43	0.38		
b2a	0.40	0.52	0.46		
С	0.35	0.41	0.38		
D	3.90	4.30	4.10		
Е	2.80	3.20	3.00		
e1	1.24	1.30	1.27		
e2	2.40	2.90	2.65		
F	0.00	0.20	_		
J	2.62 REF				
L	14.00	15.00	14.50		
La	12.90	14.90	13.90		
L1	1.55	1.75	1.65		
L3	2.00	3.00	2.50		
S	0.63	0.84	0.74		
a1	_	_	5°		
a2	_	_	5°		
а3	_	_	45°		
a4	_	_	3°		
All Dimensions in mm					



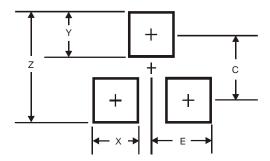
Sensor Location



Suggested Pad Layout

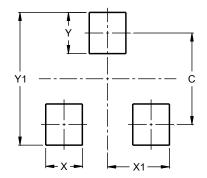
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SC59



Dimensions	Value (in mm)	
Z	3.4	
X	0.8	
Y	1.0	
С	2.4	
E	1.35	

(2) Package Type: SOT23



Dimensions	Value (in mm)	
C	2.0	
Х	0.8	
X1	1.35	
Y	0.9	
Y1	2.9	



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LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

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